TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

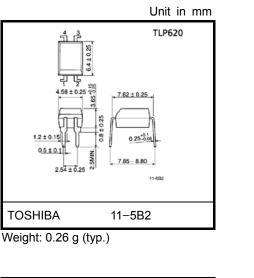
TLP620, TLP620-2, TLP620-4

Programmable Controllers AC / DC-Input Module Telecommunication

The TOSHIBA TLP620, -2 and -4 consists of a photo-transistor optically coupled to two gallium arsenide infrared emitting diode connected in inverse parallel.

The TLP620-2 offers two isolated channels in an eight lead plastic DIP, while the TLP620-4 provides four isolated channels in a sixteen plastic DIP.

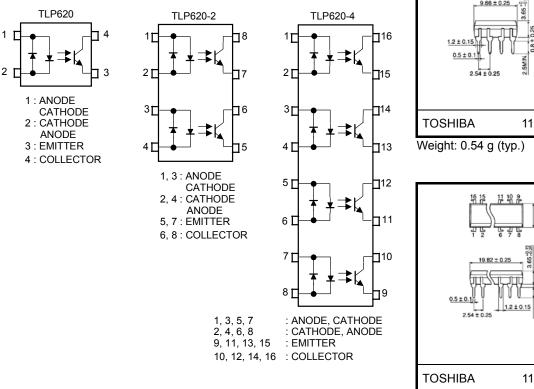
- Collector-emitter voltage: 55V (min.) •
- Current transfer ratio: 50% (min.) Rank GB: 100% (min.)



 6.4 ± 0.25

TLP620-2

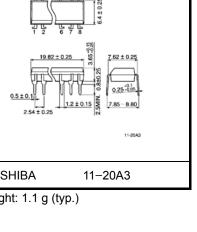
Pin Configurations (top view)



Weight: 1.1 g (typ.)

0.25 +0 7.85~8.80 11-1004 11-10C4 TLP620-4

7.62 ± 0.25



| | Made In Japan Made In Thailand | | | |
|---------------|--------------------------------|----|------------|----|
| UL recognized | E67349 | *1 | E152349 | *1 |
| BSI approved | 7426, 7427 | *2 | 7426, 7427 | *2 |

*1 UL1577

*2 BS EN60065: 2002, BS EN60950-1: 2002

- Isolation voltage: 5000V_{rms} (min.)
- Option (D4) type

VDE approved: DIN EN 60747-5-2, certificate no.40009302 Maximum operating insulation voltage: 890VPK Highest permissible over voltage: 8000VPK

(Note) When an EN 60747-5-2 approved type is needed, please designate the "Option(D4)".

• Creepage distance: 6.4mm (min.) Clearance: 6.4mm (min.) Insulation thickness: 0.4mm (min.)

Absolute Maximum Ratings (Ta = 25°C)

| | | | Rat | ing | |
|----------|---|----------------------|------------------|----------------------|------------------|
| | Characteristic | Symbol | TLP620 | TLP620–2 TLP620–4 | Unit |
| | Forward current | IF (RMS) | 60 | 50 | mA |
| | Forward current derating | ΔI _F / °C | –0.7 (Ta ≥ 39°C) | –0.5 (Ta ≥ 25°C) | mA / °C |
| Ω | Pulse forward current | IFP | 1 (100µs pul | se, 100pps) | А |
| LED | Power dissipation (1 circuit) | PD | 100 | 70 | mW |
| | Power dissipation derating | ΔP _D / °C | -1.0 | -0.7 | mW / °C |
| | Junction temperature | Tj | 12 | 25 | °C |
| | Collector-emitter voltage | V _{CEO} | 5 | 5 | V |
| | Emitter-collector voltage | V _{ECO} | 7 | 7 | V |
| ۲ | Collector current | Ι _C | 5 | 0 | mA |
| Detector | Collector power dissipation (1 circuit) | PC | 150 | 100 | mW |
| | Collector power dissipation derating (1 circuit) (Ta ≥ 25°C) | ΔP _C / °C | -1.5 | -1.0 | mW / °C |
| | Junction temperature | Tj | 12 | 25 | °C |
| Sto | rage temperature range | T _{stg} | -55~ | ·125 | °C |
| Ope | erating temperature range | T _{opr} | -55~ | -100 | °C |
| Lea | d soldering temperature | T _{sold} | 260 (| 260 (10s) | |
| Tot | al package power dissipation | PT | 250 | 150 | mW |
| | al package power dissipation ating (Ta ≥ 25°C, 1 circuit) | ΔP _T / °C | -2.5 | -1.5 | mW / °C |
| Isol | ation voltage | BVS | 5000 (AC, 1 mi | in., RH ≤ 60%) | V _{rms} |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Recommended Operating Conditions

| Characteristic | Symbol | Min. | Тур. | Max. | Unit |
|-----------------------|----------------------|------|------|------|------|
| Supply voltage | V _{CC} | _ | 5 | 24 | V |
| Forward current | I _{F (RMS)} | — | 16 | 20 | mA |
| Collector current | IC | — | 1 | 10 | mA |
| Operating temperature | T _{opr} | -25 | | 85 | °C |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

| | Characteristic | Symbol | Test Condition | Min. | Тур. | Max. | Unit |
|----------|--|-----------------------|----------------------------------|------|------|------|------|
| | Forward voltage | VF | I _F = ±10mA | 1.0 | 1.15 | 1.3 | V |
| LED | Forward current | ١ _F | $V_F = \pm 0.7 V$ | _ | 2.5 | 20 | μA |
| | Capacitance | CT | V = 0, f = 1MHz | _ | 60 | _ | pF |
| | Collector–emitter breakdown voltage | V _(BR) CEO | I _C = 0.5mA | 55 | - | _ | V |
| ctor | Emitter–collector breakdown voltage | V (BR) ECO | I _E = 0.1mA | 7 | _ | _ | V |
| Detector | Collector dark current | lana | V _{CE} = 24V | _ | 10 | 100 | nA |
| | | ICEO | V _{CE} = 24V, Ta = 85°C | _ | 2 | 50 | μA |
| | Capacitance (collector to emitter) | C _{CE} | V _{CE} = 0, f = 1MHz | _ | 10 | — | pF |

Coupled Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Condition | Mln. | Тур. | Max. | Unit |
|--------------------------------------|------------------------|---|------|------|------|------|
| Current transfer ratio | | I _F = ±5mA, V _{CF} = 5V | 50 | _ | 600 | % |
| | IC / IF | Rank GB | 100 | _ | 600 | 70 |
| Saturated CTR | | IF = ±1mA, V _{CE} = 0.4V | | 60 | — | % |
| | | Rank GB | 30 | _ | _ | 70 |
| | V _{CE (sat)} | $I_{C} = 2.4 \text{mA}, I_{F} = \pm 8 \text{mA}$ | _ | _ | 0.4 | |
| Collector–emitter saturation voltage | | $I_C = 0.2 \text{ mA}, I_F = \pm 1 \text{ mA}$ Rank GB | _ | 0.2 | _ | V |
| Voltage | | | _ | _ | 0.4 | |
| Off-state collector current | I _{C (off)} | V _F = ± 0.7V, V _{CE} = 24V | _ | 1 | 10 | μA |
| CTR symmetry | I _{C (ratio)} | $I_{C} (I_{F} = -5mA) / I_{C} (I_{F} = +5mA)$ | 0.33 | 1 | 3 | _ |

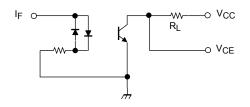
Isolation Characteristics (Ta = 25°C)

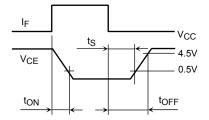
| Characteristic | Symbol | Test Condition | Min. | Тур. | Max. | Unit |
|--------------------------------|----------------|------------------------------|--------------------|------------------|------|------------------|
| Capacitance input to output | CS | V _S = 0, f = 1MHz | _ | 0.8 | _ | pF |
| Isolation resistance | R _S | V _S = 500V | 1×10 ¹² | 10 ¹⁴ | _ | Ω |
| | | AC, 1 minute | 5000 | _ | | V |
| Isolation voltage | BVS | AC, 1 second, in oil | _ | 10000 | | V _{rms} |
| | | DC, 1 minute, in oil | _ | 10000 | | V _{dc} |

Switching Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Condition | Min. | Тур. | Max. | Unit |
|----------------|------------------|--|------|------|------|------|
| Rise time | tr | | _ | 2 | _ | |
| Fall time | t _f | $V_{CC} = 10V$ | _ | 3 | _ | 116 |
| Turn–on time | t _{on} | $I_{C} = 2mA$ $R_{L} = 100\Omega$ | _ | 3 | _ | μs |
| Turn-off time | t _{off} | | _ | 3 | _ | |
| Turn–on time | t _{ON} | | _ | 2 | _ | |
| Storage time | ts | $ \begin{array}{l} R_{L} = 1.9 k \Omega & (Fig.1) \\ V_{CC} = 5V, \ I_{F} = \pm 16 m A \end{array} $ | _ | 15 | _ | μs |
| Turn-off time | tOFF | | | 25 | - | |

Fig. 1 Switching time test circuit





10⁻³ 3

3

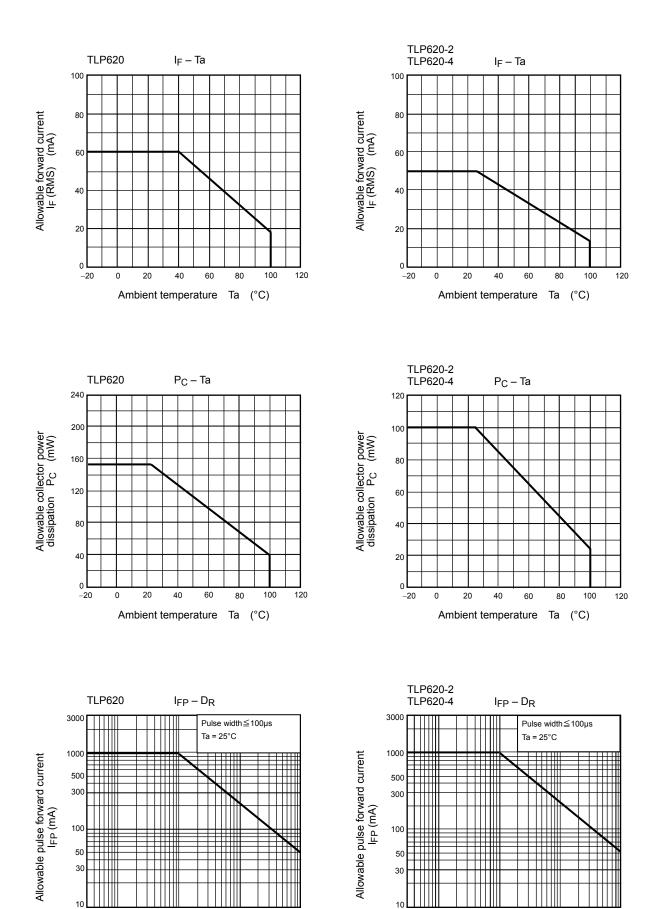
10

3 10

Duty cycle ratio DR

3

10⁰



 10^{0}

3

3

Duty cycle ratio

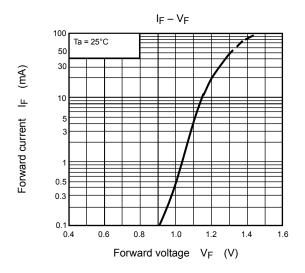
10

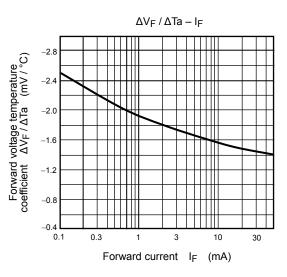
 D_R

10

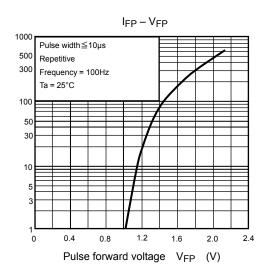
3 10

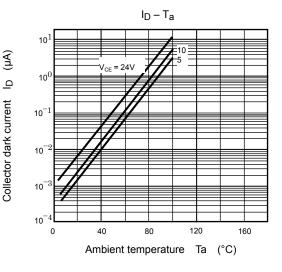
3

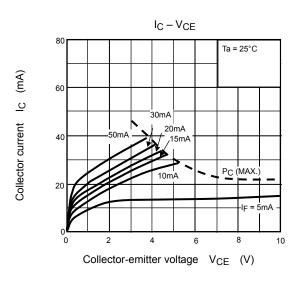


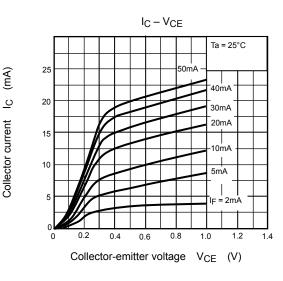


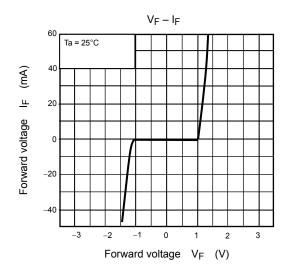


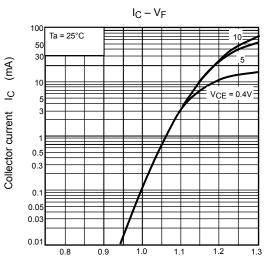




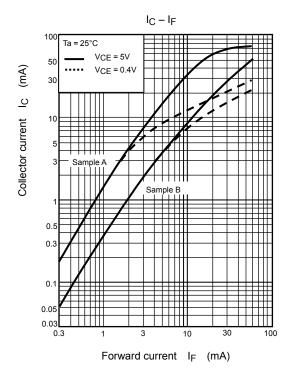


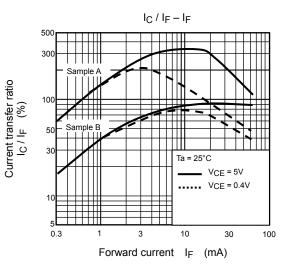


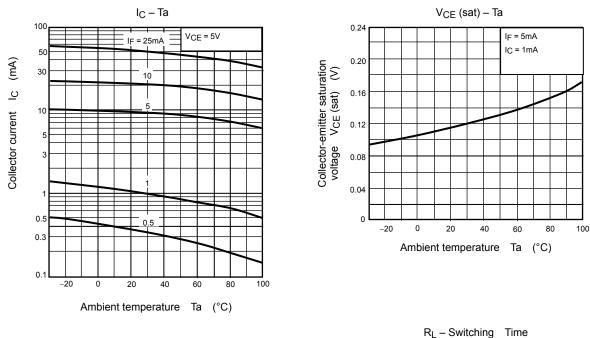


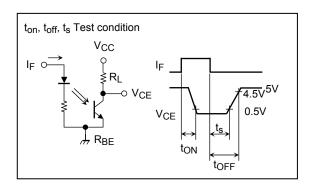


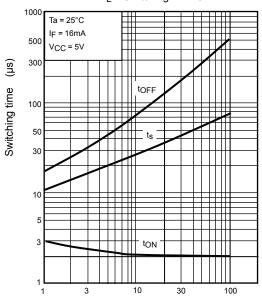
Forward voltage V_F (V)











Load resistance $\ R_L \ (k\Omega)$

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